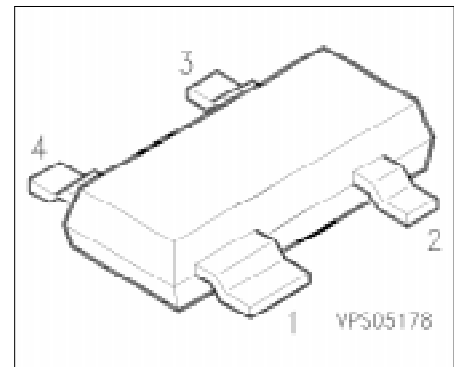


## Silicon Schottky Diode

## BAT 63

- Low barrier diode for mixer and detectors up to GHz frequencies



| Type   | Ordering Code<br>(tape and reel) | Pin Configuration |    |    |    | Marking | Package |
|--------|----------------------------------|-------------------|----|----|----|---------|---------|
|        |                                  | 1                 | 2  | 3  | 4  |         |         |
| BAT 63 | Q62702-A1004                     | A1                | C2 | A2 | C1 | 63      | SOT-143 |

### Maximum Ratings

| Parameter                 | Symbol    | Values         | Unit |
|---------------------------|-----------|----------------|------|
| Reverse voltage           | $V_R$     | 3              | V    |
| Forward current           | $I_F$     | 100            | mA   |
| Junction temperature      | $T_j$     | 150            | °C   |
| Storage temperature range | $T_{stg}$ | - 55 ... + 150 | °C   |

### Thermal Resistance

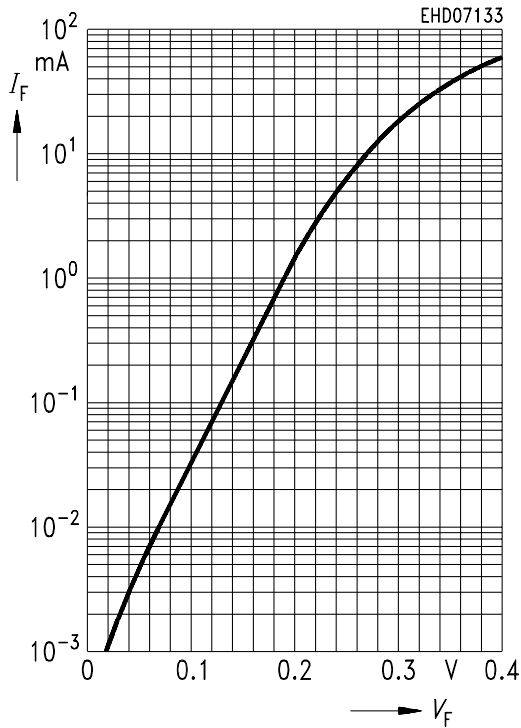
|                                |             |       |     |
|--------------------------------|-------------|-------|-----|
| Junction-ambient <sup>1)</sup> | $R_{th JA}$ | ≤ 450 | K/W |
|--------------------------------|-------------|-------|-----|

1) Package mounted on aluminum 15 mm x 16.7 mm x 0.7 mm.

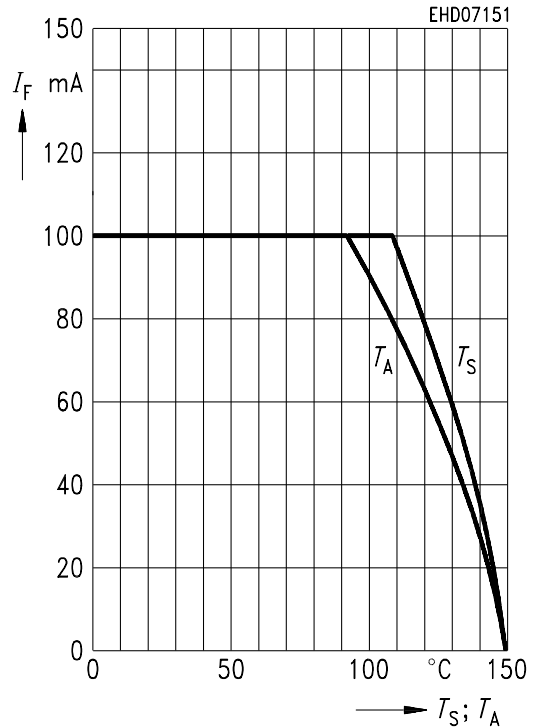
**Electrical Characteristics**at  $T_A = 25\text{ °C}$ , unless otherwise specified.

| Parameter   | Symbol | Value |      |      | Unit       |
|---|--------|-------|------|------|------------|
|   |        | min.  | typ. | max. |            |
| <b>DC Characteristics</b>                                   |        |       |      |      |            |
| Reverse current<br>$V_R = 3\text{ V}$                       | $I_R$  | –     | –    | 10   | nA         |
| Forward voltage<br>$I_F = 1\text{ mA}$                      | $V_F$  | –     | 190  | 300  | mV         |
| Diode capacitance<br>$V_R = 0.2\text{ V}, f = 1\text{ MHz}$ | $C_T$  | –     | 0.65 | 0.85 | pF         |
| Case capacitance  | $C_C$  | –     | 0.1  | –    | pF         |
| Differential resistance<br>$V = 0, f = 10\text{ kHz}$       | $R_0$  | –     | 30   | –    | k $\Omega$ |
| Series inductance   | $L_S$  | –     | 2    | –    | nH         |

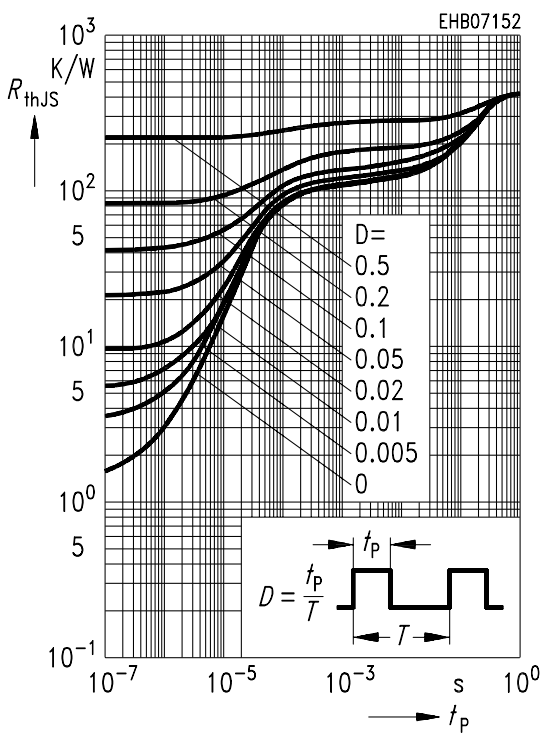
**Forward current  $I_F = f(V_F)$**



**Forward current  $I_F = f(T_S; T_A)$**



**Permissible Pulse load  $R_{thJS} = f(t_p)$**



**Permissible Pulse load  $I_{Fmax} / I_{FDC} = f(t_p)$   
 $T_A = 25\text{ °C}$**

